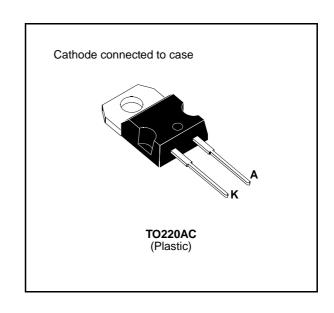


# FAST RECOVERY RECTIFIER DIODE

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSES RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING



#### SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

# **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		1000	V
V <sub>RSM</sub>	Non Repetitive Peak Reverse Voltage		1000	V
I <sub>FRM</sub>	Repetitive Peak Forward Current	t <sub>p</sub> ≤ 10μs	100	Α
I <sub>F (RMS)</sub>	RMS Forward Current		16	Α
I <sub>F (AV)</sub>	Average Forward Current	$T_c = 115^{\circ}C$ $\delta = 0.5$	8	А
I <sub>FSM</sub>	Surge Non Repetitive Forward Current	t <sub>p</sub> = 10ms Sinusoidal	50	А
Р	Power Dissipation	T <sub>c</sub> = 115°C	17	W
T <sub>stg</sub> T <sub>j</sub>	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150	°C

#### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R <sub>th (j - c)</sub>	Junction-case	2	°C/W

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### **ELECTRICAL CHARACTERISTICS**

# STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I <sub>R</sub>	T <sub>j</sub> = 25°C	$V_R = V_{RRM}$			35	μΑ
	T <sub>j</sub> = 100°C				2	mA
V <sub>F</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 8A			1.9	V
	T <sub>j</sub> = 100°C				1.8	

### RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Тур.	Max.	Unit	
t <sub>rr</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 1A	$di_F/dt = -15A/\mu s$	$V_R = 30V$			155	ns
		I <sub>F</sub> = 0.5A	$I_R = 1A$	$I_{rr} = 0.25A$			65	

# TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Тур.	Max.	Unit
t <sub>IRM</sub>	di <sub>F</sub> /dt = - 32A/μs	V <sub>CC</sub> = 200 V I <sub>F</sub> = 8A			200	ns
	$di_F/dt = -64A/\mu s$	$L_p \le 0.05 \mu H$ $T_j = 100^{\circ}C$ See Figure 1		120		
I <sub>RM</sub>	di <sub>F</sub> /dt = - 32A/μs				5.5	Α
	$di_F/dt = -64A/\mu s$			6		

# TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Conditions			Min.	Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^{\circ}C$ $d_{iF}/dt = -8A/\mu s$	$V_{CC} = 200V$ $L_p = 12\mu H$	I <sub>F</sub> = I <sub>F (AV)</sub> See figure 2			4.5	

To evaluate the conduction losses use the following equations:

$$V_F = 1.47 + 0.041 I_F$$
  $P = 1.47 \times I_{F(AV)} + 0.041 I_{F^2(RMS)}$ 

Figure 1. Turn-off switching characteristics (without series inductance).

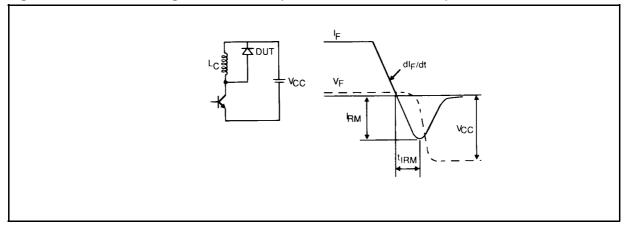
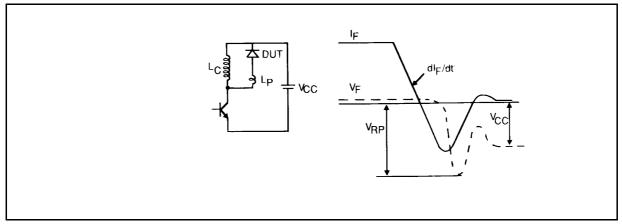
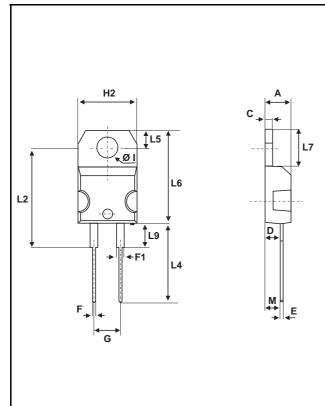


Figure 2. Turn-off switching characteristics (with series inductance).



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#### PACKAGE MECHANICAL DATA: TO220AC Plastic



		DIMEN	ISIONS	
REF.	Millin	neters	Inc	hes
	Min.	Max.	Min.	Max.
Α	4.40	4.60	0.173	0.181
С	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
Е	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.648	5 typ.
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
М	2.6	typ.	0.102	2 typ.
Diam. I	3.75	3.85	0.147	0.151

Cooling method: by conduction (method C) Marking: type number
Weight: 2.42g
Recommended torque value: 80cm. N
Maximum torque value: 100cm. N

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